**Product data sheet** 

## 1. General description

PNP low V<sub>CEsat</sub> transistor in a medium power SOT89 (SC-62) package.

NPN complement: PBSS4540X.

### 2. Features and benefits

- Low collector-emitter saturation voltage V<sub>CEsat</sub>
- High collector current capability: I<sub>C</sub> and I<sub>CM</sub>
- High efficiency leading to less heat generation.
- AEC-Q101 qualified

## 3. Applications

- Supply line switching circuits
- · Battery management applications
- DC/DC converter applications
- · Strobe flash units
- · Medium power driver (e.g. relays, buzzers and motors).

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-40	V
I <sub>C</sub>	collector current		-	-	-4	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-	-10	Α
h <sub>FE</sub>	DC current gain	$V_{CE} = -2 \text{ V}; I_{C} = -0.5 \text{ A}; T_{amb} = 25 \text{ °C}$	250	-	-	
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_C$ = -5 A; $I_B$ = -500 mA; $t_p \le 300$ μs; pulsed; $\delta \le 0.02$ ; $T_{amb}$ = 25 °C	-	45	75	mΩ



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# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter		C
2	С	collector		в
3	В	base	3 2 1	- <b>N</b>
			SOT89	sym132

# 6. Ordering information

#### Table 3. Ordering information

Type number	Package	ge				
	Name	Description	Version			
PBSS5540X	SOT89	plastic surface-mounted package; die pad for good heat transfer; 3 leads	SOT89			

## 7. Marking

#### Table 4. Marking codes

Type number	Marking code[1]
PBSS5540X	%1G

[1] % = placeholder for manufacturing site code

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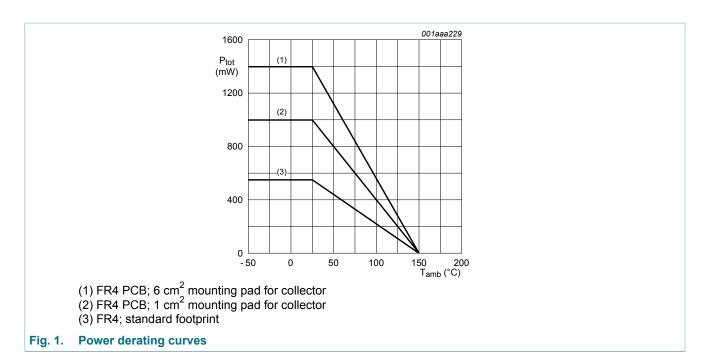
## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-40	V
$V_{CEO}$	collector-emitter voltage	open base		-	-40	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-6	V
I <sub>C</sub>	collector current			-	-4	Α
I <sub>CRM</sub>	repetitive peak collector current	$\delta \le 0.2 \; ; t_p \le 10 \; \text{ms}$		-	-5	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-10	Α
I <sub>B</sub>	base current			-	-1	Α
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-2	Α
P <sub>tot</sub>	total power dissipation		[1] [2]	-	2.5	W
		T <sub>amb</sub> ≤ 25 °C	[2]	-	0.55	W
			[3]	-	1	W
			[4]	-	1.4	W
			<u>[5]</u>	-	1.6	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- Pulsed  $t_p \le 10$  ms;  $\delta \le 0.2$  Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint. [2]
- [3] [4]
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>. Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.
- Device mounted on a 7 cm<sup>2</sup> ceramic printed-circuit board, 1 cm<sup>2</sup> single-sided copper and tin-plated.



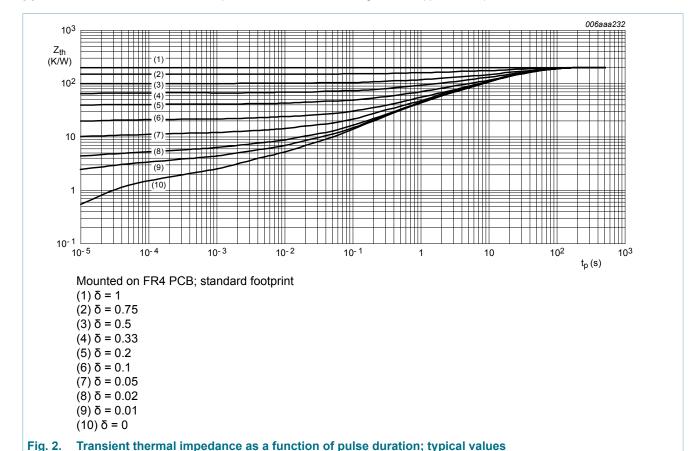
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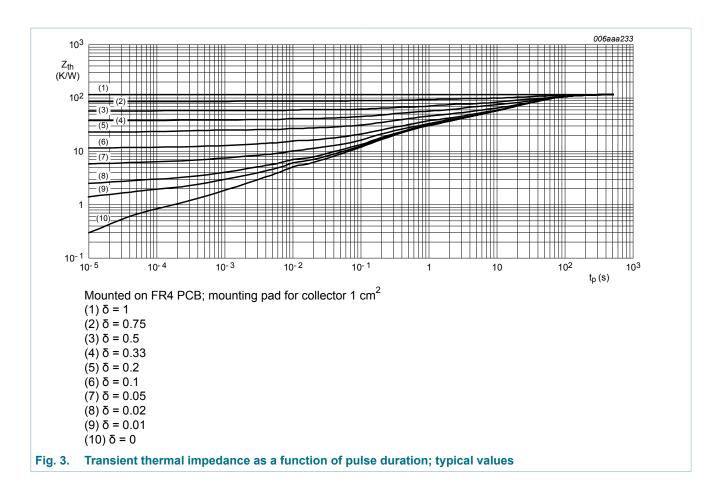
### 9. Thermal characteristics

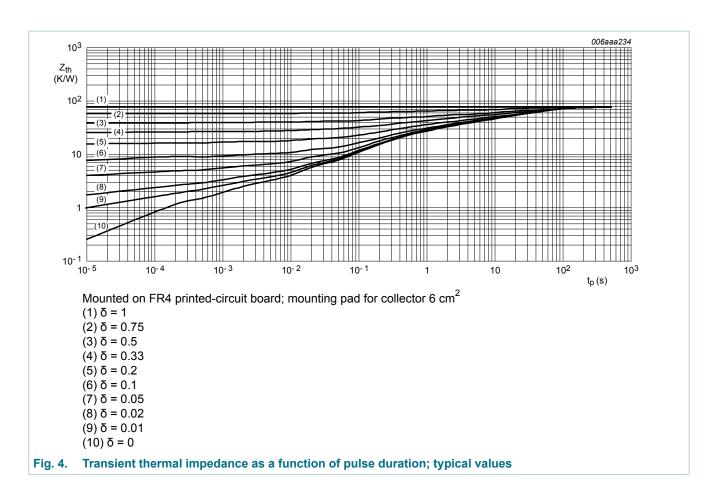
**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance	[1 [3 [4	[1] [2]	-	-	50	K/W
	from junction to ambient		[1]	-	-	225	K/W
	<b>33.3</b>		[3]	-	-	125	K/W
			[4]	-	-	90	K/W
			[5]	-	-	80	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	16	K/W

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Pulse test:  $t_0 \le 10 \text{ ms}$ ;  $\delta \le 0.2$ .
- [3]
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>. Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.
- Device mounted on a 7 cm<sup>2</sup> ceramic printed-circuit board, 1 cm<sup>2</sup> single-sided copper and tin-plated.







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## 10. Characteristics

#### **Table 7. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = -30 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
	current	$V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$	-	-	-50	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -2 V; $I_{C}$ = -0.5 A; $T_{amb}$ = 25 °C	250	-	-	
		$V_{CE}$ = -2 V; $I_{C}$ = -1 A; $t_{p}$ ≤ 300 μs; pulsed; $\delta$ ≤ 0.02 ; $T_{amb}$ = 25 °C	200	-	-	
		$V_{CE}$ = -2 V; $I_{C}$ = -2 A; $t_{p}$ ≤ 300 μs; pulsed; $\delta$ ≤ 0.02 ; $T_{amb}$ = 25 °C	150	-	-	
		$V_{CE}$ = -2 V; $I_{C}$ = -5 A; $t_{p}$ ≤ 300 μs; pulsed; $\delta$ ≤ 0.02 ; $T_{amb}$ = 25 °C	50	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -0.5 \text{ A}; I_B = -5 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$	-	-	-120	mV
		$I_C$ = -1 A; $I_B$ = -10 mA; $T_{amb}$ = 25 °C	-	-	-170	mV
		$I_C$ = -2 A; $I_B$ = -200 mA; $T_{amb}$ = 25 °C	-	-	-160	mV
		$I_C$ = -4 A; $I_B$ = -200 mA; $t_p \le 300$ μs; pulsed; $\delta \le 0.02$ ; $T_{amb}$ = 25 °C	-	-	-340	mV
		$I_C = -5 \text{ A}; I_B = -500 \text{ mA}; t_p \le 300  \mu\text{s};$	-	-	-375	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance	pulsed; $\delta \le 0.02$ ; $T_{amb} = 25 ^{\circ}C$	-	45	75	mΩ
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_C$ = -4 A; $I_B$ = -200 mA; $t_p \le 300$ μs; pulsed; $\delta \le 0.02$ ; $T_{amb}$ = 25 °C	-	-	-1.1	V
		$I_C$ = -5 A; $I_B$ = -500 mA; $t_p \le 300$ μs; pulsed; $\delta \le 0.02$ ; $T_{amb}$ = 25 °C	-	-	-1.2	V
$V_{BEon}$	base-emitter turn-on voltage	$V_{CE} = -2 \text{ V}; I_{C} = -2 \text{ A}; T_{amb} = 25 \text{ °C}$	-	-	-1	V
f <sub>T</sub>	transition frequency	$V_{CE}$ = -10 V; $I_{C}$ = -0.1 A; f = 100 MHz; $T_{amb}$ = 25 °C	60	-	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB}$ = -10 V; $I_{E}$ = 0 A; $i_{e}$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C	-	-	105	pF

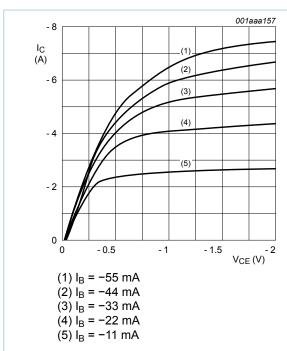


Fig. 5. Collector current as a function of collectoremitter voltage; typical values

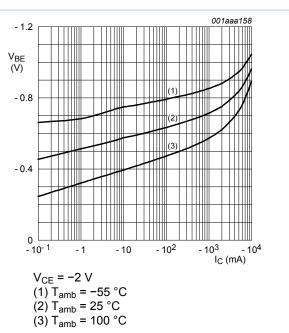


Fig. 6. Base-emitter voltage as a function of collector current; typical values

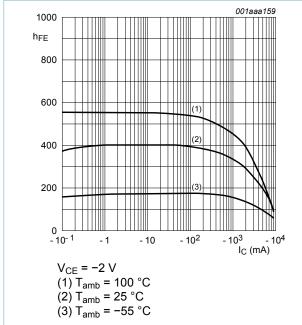


Fig. 7. DC current gain as a function of collector current; typical values

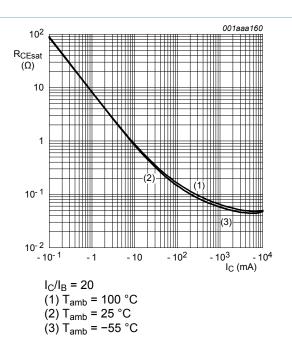


Fig. 8. Equivalent on-resistance as a function of collector current; typical values

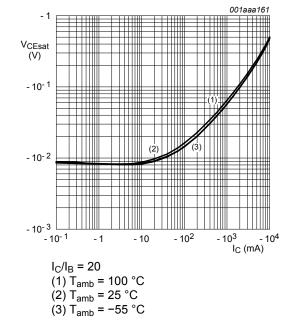


Fig. 9. Collector-emitter saturation voltage as a function of collector current; typical values

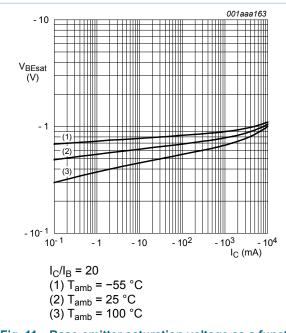


Fig. 11. Base-emitter saturation voltage as a function of collector current; typical values

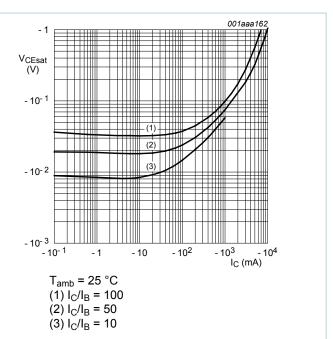


Fig. 10. Collector-emitter saturation voltage as a function of collector current; typical values

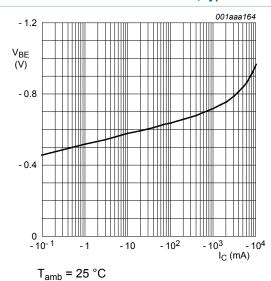


Fig. 12. Base-emitter voltage as a function of collector current; typical values

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## 11. Package outline

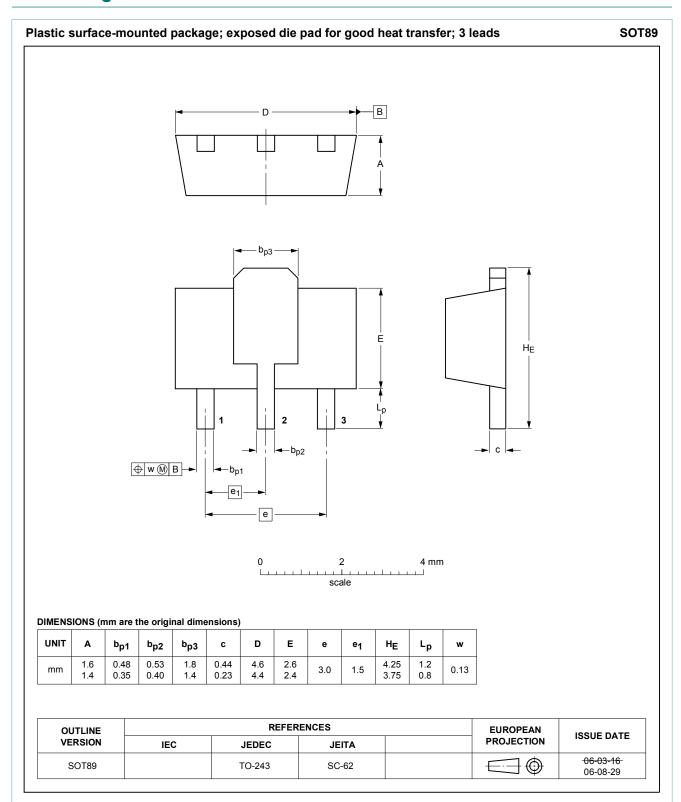
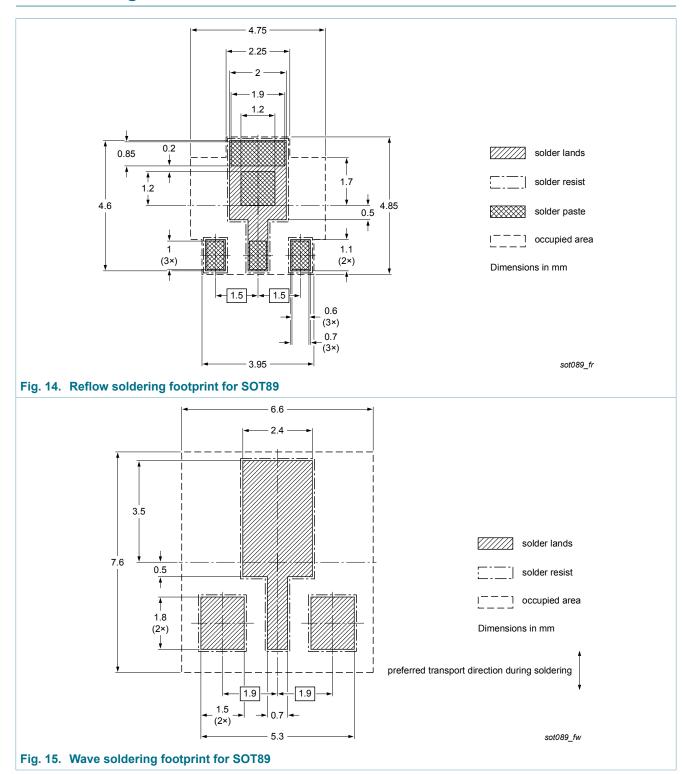


Fig. 13. Package outline SOT89

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## 12. Soldering



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# 13. Revision history

#### Table 8. Revision history

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Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS5540X v.3	20180320	Product data sheet	-	PBSS5540X v.2
Modifications:	Nexperia.	this data sheet has been redeave been adapted to the new condendanced		, ,
PBSS5540X v.2	20041104	Product data sheet	-	PBSS5540X v.1
PBSS5540X v.1	20040115	Product data sheet	-	-

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## 14. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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